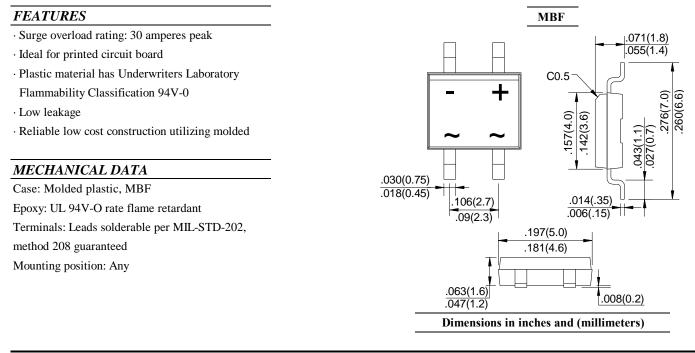
MB05F THRU MB10F





REVERSE VOLTAGE: FORWARD CURRENT:

50 to 1000 VOLTS 0.5 AMPERE



Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, $60H_Z$, resistive or inductive load. For capacitive load, derate current by 20%.

	Symbols	MB05F	MB1F	MB2F	MB4F	MB6F	MB8F	MB10F	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current				-			•		
(see Fig. 1) on glass-epoxy P.C.B (Note 2)	I _(AV)				0.5				Amp
on aluminum substrate (Note 3)	0.8								
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I _{FSM}	30							Amp
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage	V	1.05							Volts
at 0.4A DC and 25°C	V _F								
Maximum Reverse Current at T _A =25°C	т	5.0 100							uAmp
at Rated DC Blocking Voltage T _A =125°C	I _R								
Typical Junction Capacitance (Note 1)	CJ				13				pF
Typical Thermal Resistance (Note 3)	R _{0JA}				70				°C/W
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$				20				°C/W
Operating and Storage Temperature Range	T _J , Tstg				-55 to +15	0			°C

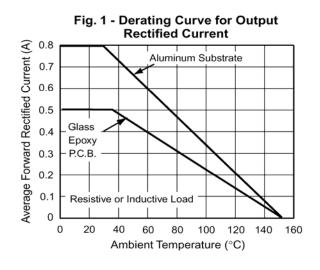
NOTES:

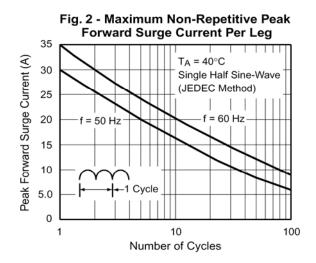
1- Measured at 1 $\ensuremath{\text{MH}}_{Z}$ and applied reverse voltage of 4.0 VDC.

2- On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3mm) pads

3- On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20 x 20mm) mounted on 0.05 x 0.05" (1.3 x 1.3mm) solder pad

RATINGS AND CHARACTERISTIC CURVES





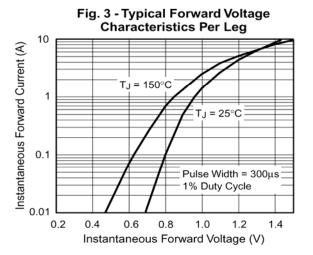


Fig. 5 - Typical Junction Capactitance Per Leg 30 TJ = 25°C 25 Junction Capacitance (pF) f = 1 MHz Vsig = 50mVp-p 20 15 10 5.0 0 0.1 100 200 10 1 Reverse Voltage (V)

Fig. 4 - Typical Reverse Leakage Characteristics Per Leg

